

Supporting Information for

## BiVO<sub>4</sub> Photoanode with Exposed (040) Facets for Enhanced Photoelectrochemical Performance

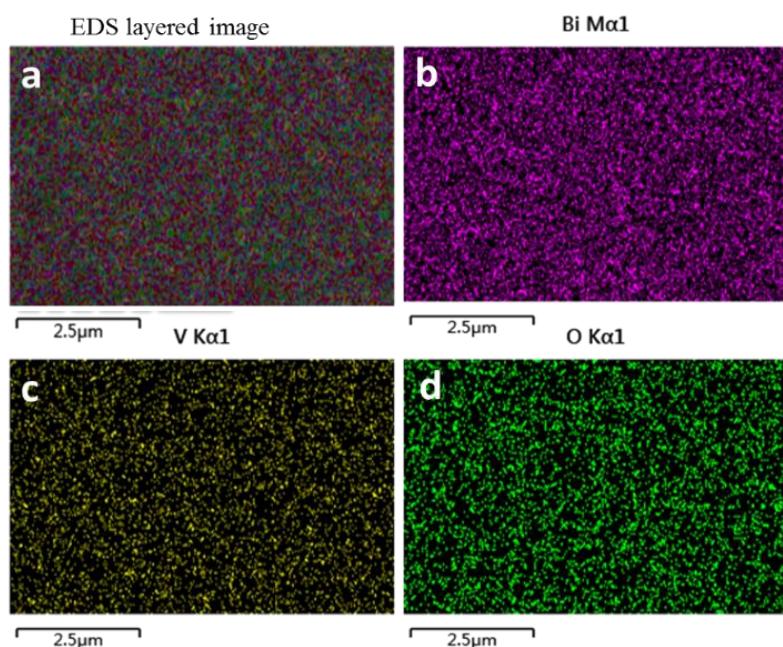
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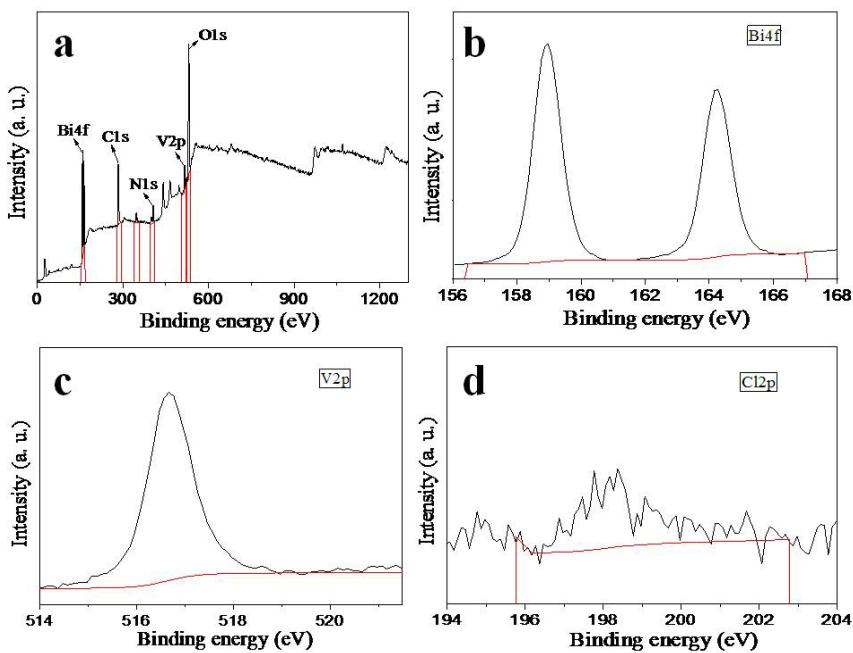
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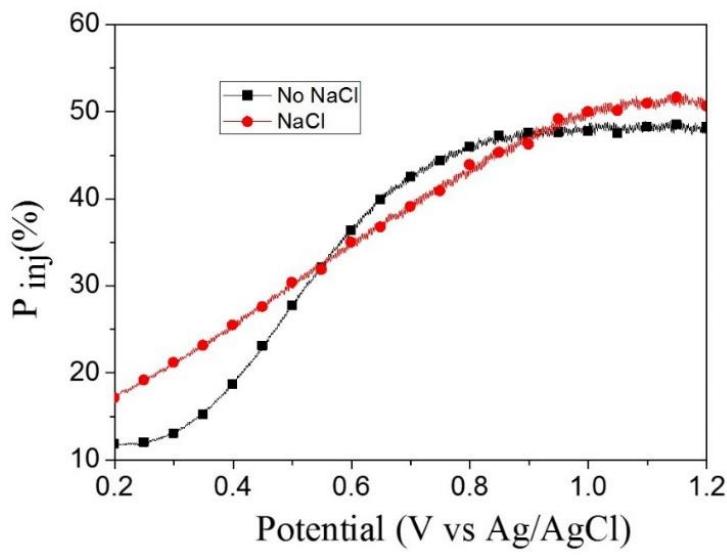
### 1 Figures and Table



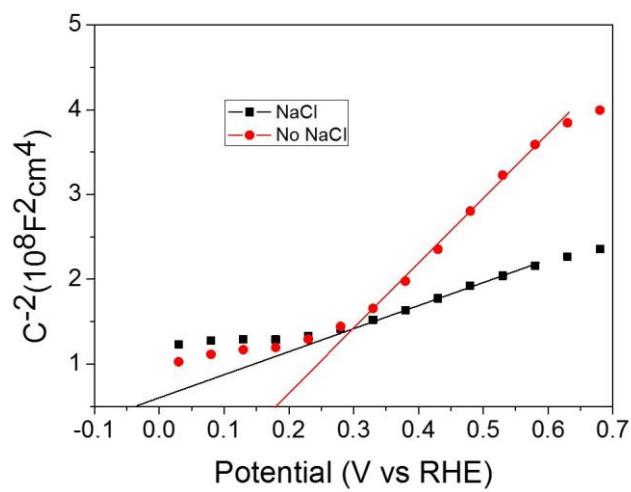
**Fig. S1** **a** EDS layered image and the corresponding STEM-EDS elemental mapping images of **b** Bi, **c** V, and **d** O



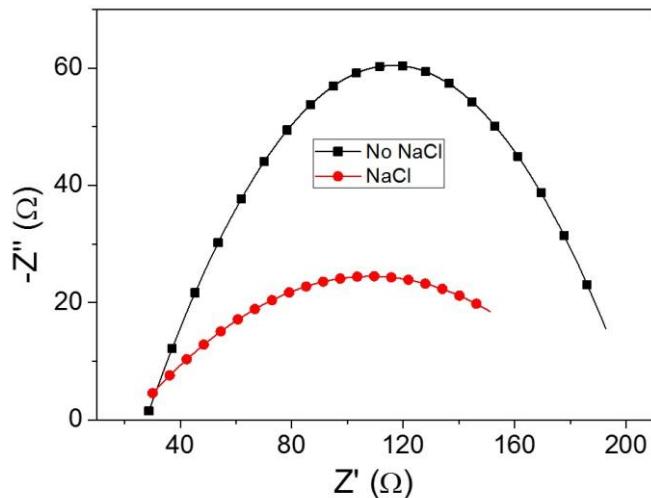
**Fig. S2** **a** XPS survey data and **b** Bi 4f, **c** V 2p, **d** Cl 2p spectra of BiVO<sub>4</sub> films prepared without NaCl



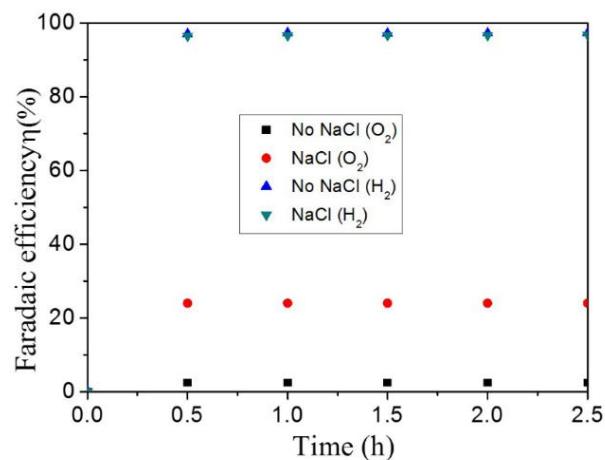
**Fig. S3** Charge injection efficiency versus potential curves of BiVO<sub>4</sub> films prepared with and without NaCl



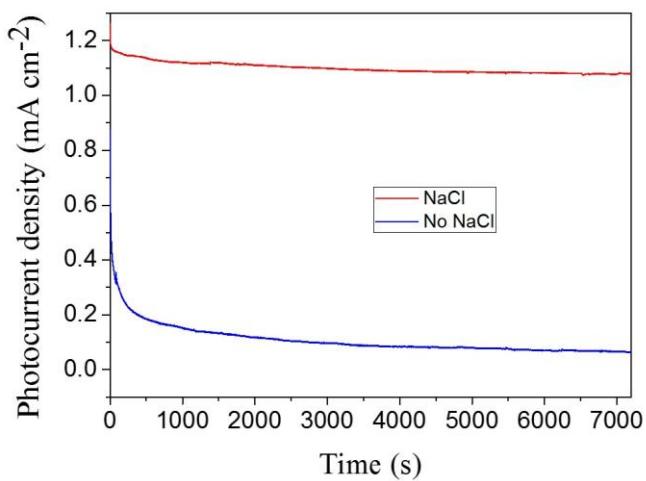
**Fig. S4** Mott–Schottky plots for  $\text{BiVO}_4$  photoanodes prepared with and without  $\text{NaCl}$



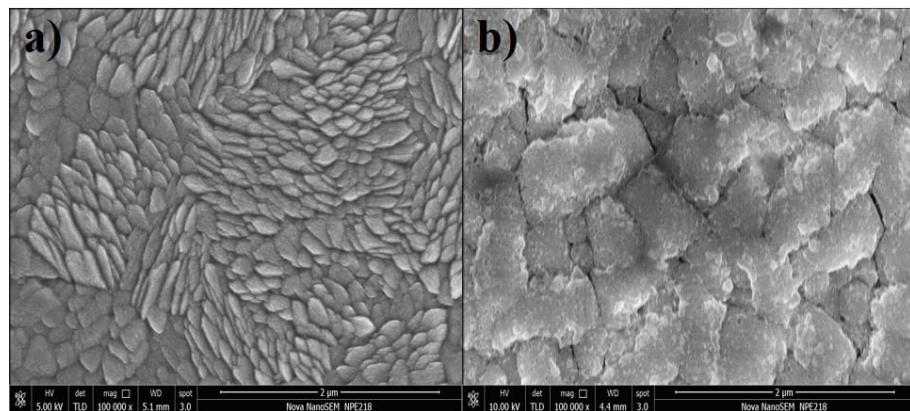
**Fig. S5** Nyquist plots of the  $\text{BiVO}_4$  photoanodes prepared with and without  $\text{NaCl}$



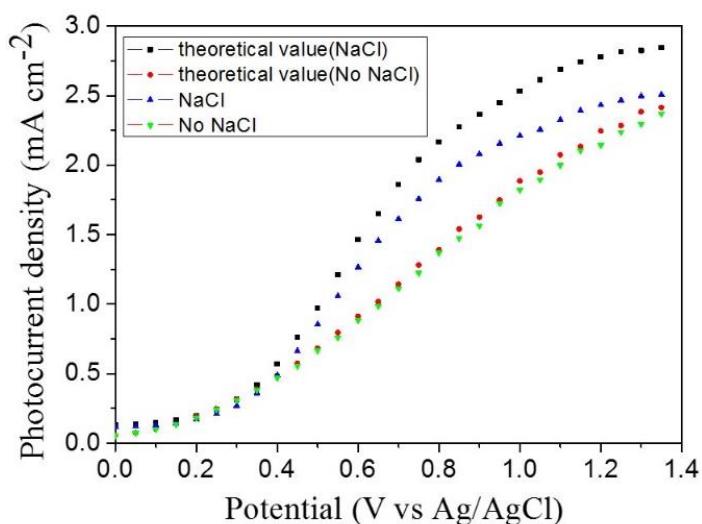
**Fig. S6** Faradaic efficiency of the  $\text{BiVO}_4$  photoanodes for water oxidation



**Fig. S7**  $I-t$  curves of  $\text{BiVO}_4$  photoanodes prepared with and without  $\text{NaCl}$  at 1.23 V vs RHE under AM 1.5G illumination



**Fig. S8** SEM images of  $\text{BiVO}_4$  photoanodes prepared with **a** and without **b**  $\text{NaCl}$  after water splitting



**Fig. S9** The comparison of the theoretical and measured photocurrent density

The theoretical current density was slightly higher than the measured one (shown in Figure. S9), which may be ascribed to the limitations of the equation (Photocurrent density=theoretical maximum photocurrent value × light absorption efficiency × charge transfer efficiency × charge transport efficiency × faradaic efficiency) especially the theoretical maximum photocurrent density achievable assuming 100% IPCE for photons with energy  $\geq E_g$  and calculated  $J_{abs}$  assuming 100% APCE. The detailed calculation process can be referred to the literature [5].

**Table S1** Comparison of photoactivities with similar BiVO<sub>4</sub> photoanodes

Bare BiVO <sub>4</sub>	Photocurrent density (mA cm <sup>-2</sup> @1.23 Vvs RHE)	IPCE@400 nm	Reference
<0.5 (200 mW cm <sup>-2</sup> )	/	[1]	
<0.1 (158 mW cm <sup>-2</sup> )	/	[2]	
0.94 (100 mW cm <sup>-2</sup> )	42.1% @1.6 Vvs RHE	[3]	
0.25 (100 mW cm <sup>-2</sup> )	/	[4]	
1.26 (100 mW cm <sup>-2</sup> )	>35%	This work	

## 2 Transient Photocurrent Analyses

The decay curves were fitted to a second-order exponential function [6-8],

$$y = y_0 + A_1 e^{-x/\tau_1} + A_2 e^{-x/\tau_2}$$

where  $\tau_1$  and  $\tau_2$  are the time constants and  $A_1$  and  $A_2$  are the probability constants. The percentage of  $\tau_1$  ( $\varphi_1$ ) was calculated as Eq. S1

$$\varphi_1 = \frac{A_1}{A_1 + A_2} \times 100\% \quad (\text{S1})$$

and the percentage of  $\tau_2$  ( $\varphi_2$ ) was calculated as Eq. S2

$$\varphi_2 = \frac{A_2}{A_1 + A_2} \times 100\% \quad (\text{S2})$$

The average decay time ( $\tau$ ) was calculated as Eq. S3

$$\tau = \tau_1 \varphi_1 + \tau_2 \varphi_2 \quad (\text{S3})$$

## References

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